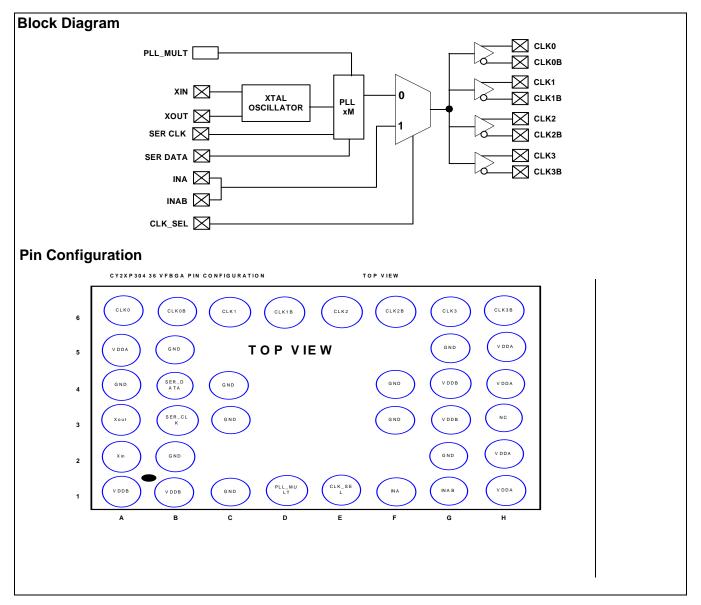


# High-Frequency Programmable PECL Clock Generation Module

### **Features**

- 40 ps typical peak-peak period jitter at 125 MHz
- 30 ps typical output-output skew at 400 MHz
- Four low-skew LVPECL outputs
- Phase-locked loop (PLL) multiplier select
- · Serially-configurable multiply ratios
- Eight-bit feedback counter and six-bit reference counter for high accuracy

- HSTL inputs—HSTL-to-LVPECL level translation
- 125- to 500-MHz output range for high-speed applications
- High-speed PLL bypass mode to 1.5 GHz
- 36-VFBGA, 6 × 8 × 1 mm
- 3.3V operation





### **Pin Definitions**

Pin #	Pin Name	Pin Description
A1,B1,G3,G4	VDDB	3.3V Power Supply for Crystal Driver
A2	XIN	Reference Crystal Input
A3	XOUT	Reference Crystal Feedback
A4,B2,C1,C3,C4,F3,F4,G2,G5,B5	GND	Ground
A5,H1,H2,H4,H5	VDDA	3.3V Power Supply
A6	CLK0	LVPECL Clock Output
B6	CLK0B	LVPECL Clock Output (Complement)
C6	CLK1	LVPECL Clock Output
D6	CLK1B	LVPECL Clock Output (Complement)
E6	CLK2	LVPECL Clock Output
F6	CLK2B	LVPECL Clock Output (Complement)
G6	CLK3	LVPECL Clock Output
H6	CLK3B	LVPECL Clock Output (Complement)
B3	SER_CLK	Serial Interface Clock
B4	SER_DATA	Serial Interface Data
D1	PLL_MULT	PLL Multiplier Select Input, Internal pull-up resistor, see Frequency Table
E1	CLK_SEL	Clock Select Input, Internal Pull down. HIGH select INA/INAB, Internal PLL is bypassed. LOW select internal PLL
F1,G1	INA,INAB	Differential Clock Input pair, used in PLL-bypassed mode
H3	NC	No Connect

## **Frequency Table**

PLL_Mult	M (PLL Multiplier)	Example Input Crystal Frequency	CLK[0:3],CLKB[0:3]
0	x16	25 MHz	400 MHz
		31.25 MHz	500 MHz
1	x8	15.625 MHz	125 MHz

#### CY2XP304 Two-Wire Serial Interface

#### Introduction

The CY2XP304 has a two-wire serial interface designed for data transfer operations, and is used for programming the P and Q values for frequency generation.  $S_{\text{clk}}$  is the serial clock line controlled by the master device.  $S_{\text{data}}$  is a serial bidirectional data line. The CY2XP304 is a slave device and can either read or write information on the dataline upon request from the master device.

Figure 1 shows the basic bus connections between master and slave device. The buses are shared by a number of devices and are pulled HIGH by a pull-up resistor.

## **Serial Interface Specifications**

Figure 2 shows the basic transmission specification. To begin and end a transmission, the master device generates a start signal (S) and a stop signal (P). Start (S) is defined as switching the  $S_{data}$  from HIGH to LOW while the  $S_{clk}$  is at HIGH. Similarly, stop (P) is defined as switching the  $S_{data}$  from LOW to HIGH while holding the  $S_{clk}$  HIGH. Between these two signals, data on  $S_{data}$  is synchronous with the clock on the  $S_{clk}$ .

Data is allowed to change only at LOW period of clock, and must be stable at the HIGH period of clock. To acknowledge, drive the  $S_{\text{data}}$  LOW before the  $S_{\text{clk}}$  rising edge and hold it LOW until the  $S_{\text{clk}}$  falling edge.

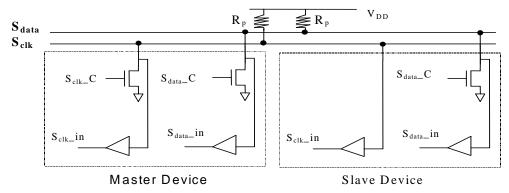
### **Serial Interface Format**

Each slave carries an address. The data transfer is initiated by a start signal (S). Each transfer segment is one byte in length. The slave address and the read/write bit are first sent from the master device after the start signal. The addressed slave device must acknowledge (Ack) the master device. Depending on the Read/Write bit, the master device will either write data into (logic 0) or read data (logic 1) from the slave device. Each time a byte of data is successfully transferred, the receiving device must acknowledge. At the end of the transfer, the master device will generate a stop signal (P).

#### **Serial Interface Transfer Format**

Figure 2 shows the serial interface transfer format used with the CY2XP304. Two dummy bytes must be transferred before the first data byte. The CY2XP304 has only three bytes of latches to store information, and the third byte of data is reserved. Extra data will be ignored.





**Figure 1. Device Connections** 

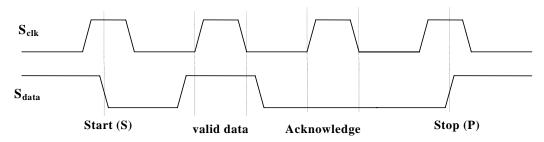


Figure 2. Serial Intertace Specifications

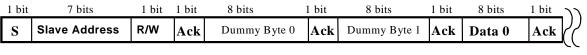




Figure 3. CY2XP304 Transfer Format

### Serial Interface Address for the CY2XP304

A6	A5	A4	А3	A2	A1	A0	R/W
1	1	0	0	1	0	1	0

### Serial Interface Programming for the CY2XP304

	b7	b6	b5	b4	b3	b2	b1	b0
Data0	QCNTBYP	SELPQ	Q<5>	Q<4>	Q<3>	Q<2>	Q<1>	Q<0>
Data1	P<7>	P<6>	P<5>	P<4>	P<3>	P<2>	P<1>	P<0>
Data2	Reserved							

To program the CY2XP304 using the two-wire serial interface, set the SELPQ bit HIGH. The default setting of this bit is LOW. The P and Q values are determined by the following formulas:

$$P_{final} = (P_{7..0} + 3) * 2$$

 $Q_{final} = Q_{5..0} + 2$ 

If the QCNTBYP bit is set HIGH, then  $\mathbf{Q}_{\text{final}}$  defaults to a value of 1. The default setting of this bit is LOW.

If the SELPQ bit is set LOW, the PLL multipliers will be set using the values in the Select Function Table.

CyberClocks $^{\text{TM}}$  has been developed to generate P and Q values for stable PLL operation. This software is downloadable from www.cypress.com.



### PLL Frequency = Reference x P/Q = Output

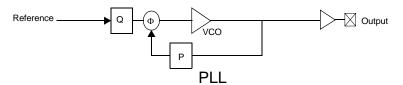


Figure 4. PLL Block Diagram

## **Functional Specifications**

### **Crystal Input**

The CY2XP304 receives its reference from an external crystal. Pin XIN is the reference crystal input, and pin XOUT is the reference crystal feedback. The parameters for the crystal are given on page 5 of this data sheet. The oscillator circuit requires external capacitors. Please refer to the application note entitled *Crystal Oscillator Topics* for details.

### **Select Input**

There are two select input pins, the PLL\_MULT and CLK\_SEL. PLL\_MULT pin selects the frequency multiplier in the PLL, and is a standard LVCMOS input. The S pin has an internal pull-up resistor. The multiplier selection is given on page 2 of this data sheet (see *Frequency Table*).

### **State Transition Characteristics**

Specifies the maximum settling time of the CLK and CLKB outputs from device power-up. For  $V_{DD}$  and  $V_{DDX}$  any sequences are allowed to power-up and power-down the CY2XP304.

### **State Transition Characteristics**

From	То	Transition Latency	Description
V <sub>DD</sub> /V <sub>DDX</sub> On	CLK/CLK B Normal		Time from V <sub>DD</sub> /V <sub>DDX</sub> is applied and settled to CLK/CLKB outputs settled.



### **Absolute Maximum Conditions**

Parameter	Description	Condition	Min.	Max.	Unit
V <sub>CC</sub>	Supply Voltage	Non-functional	-0.3	4.6	V
V <sub>CC</sub>	Operating Voltage	Functional	3.135	3.465	V
VTT	Output Termination Voltage	Relative to V <sub>CC</sub> <sup>[1]</sup>	V <sub>C</sub>	C-2	V
V <sub>IN</sub>	Input Voltage	Relative to V <sub>CC</sub> <sup>[1]</sup>	-0.3	V <sub>CC</sub> + 0.3	V
V <sub>OUT</sub>	Output Voltage	Relative to V <sub>CC</sub> <sup>[1]</sup>	-0.3	V <sub>CC</sub> + 0.3	V
LU <sub>I</sub>	Latch Up Immunity	Functional	1	00	mA
T <sub>S</sub>	Temperature, Storage	Non-functional	-65	+150	°C
T <sub>A</sub>	Temperature, Operating Ambient	Functional	-40	+85	°C
T <sub>J</sub>	Temperature, Junction	Non-functional	_	150	°C
Ø <sub>Jc</sub>	Dissipation, Junction to Case	Functional	11	.38	°C/W
Ø <sub>Ja</sub>	Dissipation, Junction to Ambient	Functional	85	5.83	°C/W
ESD <sub>h</sub>	ESD Protection (Human Body Model)		20	000	V
M <sub>SL</sub>	Moisture Sensitivity Level			3	N.A.
G <sub>ATES</sub>	Total Functional Gate Count	Assembled die	!	50	Ea.

## **Crystal Requirements**

Requirements to use parallel mode fundamental xtal. External capacitors are required in the crystal oscillator circuit. Please refer to the application note entitled *Crystal Oscillator Topics* for details.

## **Crystal Requirements**

Parameter	Description	Min.	Max.	Unit
X <sub>F</sub>	Frequency	10	31.25	MHz

## **DC Electrical Specifications**

Parameter	Description	Min.	Max.	Unit
$V_{DD}$	Supply voltage	3.135	3.465	V
$V_{IL}$	Input signal low voltage at pin PLL_MULT	_	0.35	V
V <sub>IH</sub>	Input signal high voltage at pin PLL_MULT	0.65	_	V
R <sub>PUP</sub>	Internal pull-up resistance	10	100	kΩ
t <sub>PU</sub>	Power-up time for all V <sub>DD</sub> s to reach minimum specified voltage (power ramps must be monotonic)	0.05	500	ms

## **Operating Conditions**

Parameter	Description	Min.	Max.	Unit
T <sub>A</sub>	Commercial Temperature	0	70	°C
	Industrial Temperature	-40	85	°C

#### Note:

1. Where V<sub>CC</sub> is 3.3V±5%.



## **DC Specifications** ( $V_{CC} = 3.3 \text{ V} \pm 5\%$ , Commercial and Industrial temp.)

Parameter	Description	Condition	Min.	Max.	Unit
Clock Input P	air INA, INAB (HSTL differential sig	nals)	-		1
$V_{DIF}$	HSTL Differential Input Voltage <sup>[2]</sup>		0.4	1.9	V
V <sub>X</sub>	HSTL Differential Crosspoint Voltage <sup>[3]</sup>		0.68	0.9	V
I <sub>IN</sub>	Input Current	$V_{IN} = V_X \pm 0.2V$		150	μА
PECL Output	s CLK[0:3], CLK[0:3]B (PECL differ	ential signals)			•
V <sub>OL</sub>	Output Low Voltage V <sub>CC</sub> = 3.3V ± 5%	$I_{OL} = -5 \text{ mA}^{[4]}$	V <sub>CC</sub> – 1.995	V <sub>CC</sub> – 1.5	V
V <sub>OH</sub>	Output High Voltage	$I_{OH} = -30 \text{ mA}^{[4]}$	V <sub>CC</sub> – 1.25	V <sub>CC</sub> - 0.7	V
Supply Curre	nt and V <sub>BB</sub>				•
I <sub>EE</sub>	Maximum Quiescent Supply Current without Output Termination Current			150	mA
C <sub>IN</sub>	Input Pin Capacitance	INA, INAB		3	pF
L <sub>IN</sub>	Pin Inductance			1	nΗ

## AC Electrical Specifications Dinput

Parameter	Description	Min.	Max.	Unit
f <sub>IN</sub>	Input frequency with driven reference, crystal inputs	1	133	MHz
f <sub>XTAL,IN</sub>	Input frequency with crystal input	10	31.25	MHz
f <sub>INA_IN</sub>	Input Frequency with INA/INAB inputs	0	1500	MHz
C <sub>IN,CMOS</sub>	Input capacitance at PLL_MULT pin <sup>[5]</sup>	_	10	pF

## AC Specifications DPECL Clock Outputs CLK[0:3], CLK[0:3]B

Parameter	Description	Conditions	Min.	Тур.	Max.	Unit
f <sub>O</sub>	Output Frequency	CLK_SEL = 0	125	_	500	MHz
		CLK_SEL = 1	0	_	1500	MHz
Vo <sub>(P-P)</sub>	Differential output voltage (peak-to-peak)	f <sub>O</sub> < 1GHz	0.375	_	-	V
V <sub>CMRO</sub>	Output Common Voltage Range			V <sub>CC</sub> - 1.425		V
tsk <sub>(O)</sub>	Output-to-output skew	400-MHz 50% duty cycle Standard load Differential Operation	-	30	50	ps
tsk <sub>(PP)</sub>	Part-to-part output skew	400-MHz 50% duty cycle Standard load Differential Operation	-	_	150	ps
$T_R,T_F$	Output Rise / Fall time	400-MHz 50% duty cycle Differential 20% to 80%	-	_	0.3	ns
DC	Long-term average output duty cycle		45	_	55	%
t <sub>DC,ERR</sub>	Cycle-cycle duty cycle error at x8 with 15.625-MHz input		-	_	70	ps
Phase Noise	Phase Noise at 10 kHz (x8 mode) @ 125 MHz		-107	_	-92	dBc
BW <sub>LOOP</sub>	PLL Loop Bandwidth			50		kHz (-3dB)

### Notes:

- V<sub>DIF</sub> (DC) is the amplitude of the differential HSTL input voltage swing required for device functionality.
  V<sub>X</sub> (DC) is the crosspoint of the differential HSTL input signal. Functional operations is obtained when the crosspoint is within the V<sub>X</sub> (DC) range and the input swing lies within the V<sub>DIF</sub> (DC) specification.
  Equivalent to a termination of 50Ω to V<sub>TT</sub>.
  Capacitance measured at freq. = 1 MHz, DC Bias = 0.9V, and VAC < 100 mV.</li>



## **AC Specifications** DPECL Clock Outputs CLK[0:3], CLK[0:3]B (continued)

Parameter	Description	Conditions	Min.	Тур.	Max.	Unit
t <sub>JCRMS</sub>	Cycle-to-cycle RMS jitter	At 125-MHz frequency	_	12.1	15	ps
		At 400-MHz frequency	_	8.2	10	ps
		At 500-MHz frequency	_	9.7	12	ps
<sup>t</sup> JCPK	Cycle-to-cycle jitter (pk-pk)	At 125-MHz frequency	_	72	95	ps
		At 200-MHz frequency, XF = 25 MHz	-	50	65	ps
		At 400-MHz frequency	_	40	55	ps
		At 500-MHz frequency	-	50	65	ps
t <sub>JPRMS</sub>	Period jitter RMS	At 125-MHz frequency	-	5.7	6.8	ps
		At 400-MHz frequency	_	4.5	5.6	ps
		At 500-MHz frequency	-	5.6	6.8	ps
t <sub>JPPK</sub>	Period jitter (pk-pk)	At 125-MHz frequency	_	4.0	55	ps
		At 200-MHz frequency, XF = 25 MHz	_	38	50	ps
		At 400-MHz frequency	_	34	45	ps
		At 500-MHz frequency	-	39	50	ps
t <sub>JLT</sub>	Long term RMS Jitter (P < 20)	At 125-MHz frequency	_	_	25	ps
		At 400-MHz frequency	_	_	20	ps
		At 500-MHz frequency	_	_	25	ps
t <sub>JLT</sub>	Long term RMS Jitter (20 < P < 40)	At 125-MHz frequency	_	_	55	ps
		At 400-MHz frequency	_	_	65	ps
		At 500-MHz frequency	_	_	55	ps
t <sub>JLT</sub>	Long-term RMS Jitter (40 < P < 60)	At 125-MHz frequency	_	_	70	ps
		At 400-MHz frequency	-	_	90	ps
		At 500-MHz frequency	-	_	65	ps

## AC Electrical Specifications DPECL Clock Outputs: PLL Bypass Mode

Parameter	Description	Conditions	Min	Max	Unit
Vo <sub>(P-P)</sub>	Differential output voltage (peak-to-peak)	Differential PRBS fo < 1.0 GHz	0.375	_	V
J <sub>P</sub>	Period Jitter	660 MHz 50% duty cycle Standard load	_	1.3	ps r.m.s.
T <sub>PD</sub>	Propagation delay (INA/INAB to output)	PECL, 660MHz	280	650	ps
		HSTL, <1 GHz	280	750	ps

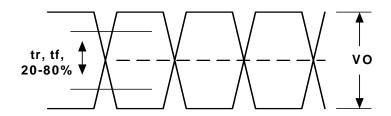


Figure 5. ECL/LVPECL Output

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#### **Jitter**

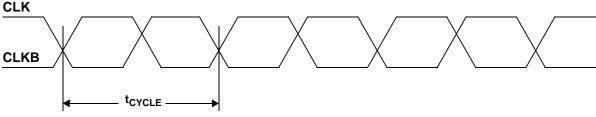
This section defines the specifications that relate to timing uncertainty (or jitter) of the input and output waveforms. Figure 6 shows the definition of period jitter with respect to the falling edge of the CLK signal. Period jitter is the difference between the minimum and maximum cycle times over many cycles (typically 12800 cycles at 400 MHz). Equal requirements apply for rising edges of the CLK signal.  $t_{\rm JP}$  is defined as the output period jitter.

Figure 7 shows the definition of cycle-to-cycle jitter with respect to the falling edge of the CLK signal. Cycle-to-cycle jitter is the difference between cycle times of adjacent cycles over many cycles (typically 12800 cycles at 400 MHz). Equal

requirements apply for rising edges of the CLK signal.  $t_{\text{JC}}$  is defined as the clock output cycle-to-cycle jitter.

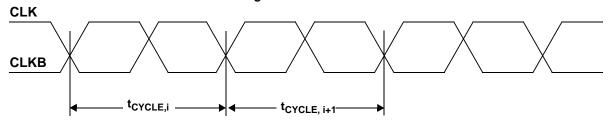
Figure 8 shows the definition of cycle-to-cycle duty cycle error. Cycle-to-cycle duty cycle error is defined as the difference between high-times of adjacent cycles over many cycles (typically 12800 cycles at 400 MHz). Equal requirements apply to the low-times.  $t_{DC\to ERR}$  is defined as the clock output cycle-to-cycle duty cycle error.

Figure 9 shows the definition of long-term jitter error. Long-term jitter is defined as the accumulated timing error over many cycles (typically 12800 cycles at 400 MHz). It applies to both rising and falling edges.  $t_{JLT}$  is defined as the long-term iitter.



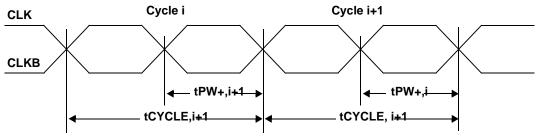
t<sub>JP</sub> = t<sub>CYCLE, max</sub> - t<sub>CYCLE, min. over many cycles</sub>

Figure 6. Period Jitter



t<sub>JC</sub> = t<sub>CYLCE,i</sub> - t<sub>CYCLE,i+1</sub> over many consecutive cycles

Figure 7. Cycle-to-cycle Jitter



 $t_{DC,ERR} = t_{PW+,i} - t_{PW+,i+1}$  over many consecutive cycles

Figure 8. Cycle-to-cycle Duty Cycle Error

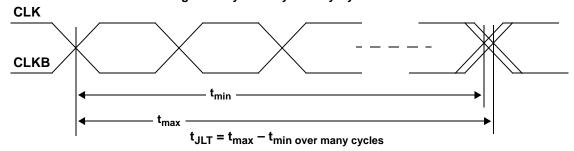


Figure 9. Long-term Jitter



## **Test Configurations**

Standard test load using a differential pulse generator and differential measurement instrument.

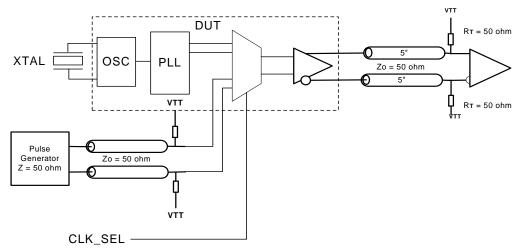


Figure 10. CY2XP304 AC Test Reference

## **Applications Information**

### **Termination Examples**

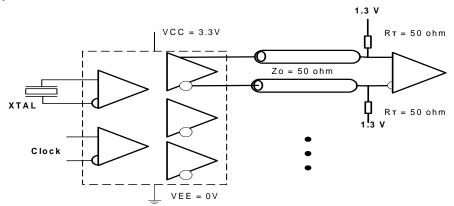


Figure 11. Standard LVPECL-PECL Output Termination

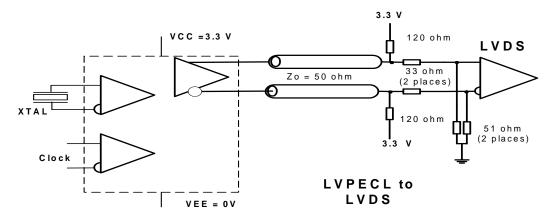


Figure 12. Low-Voltage Positive Emitter-Coupled Logic (LVPECL) to a Low-voltage Differential Signaling (LVDS) Interface

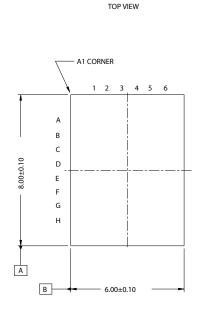


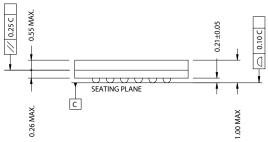
## **Ordering Information**

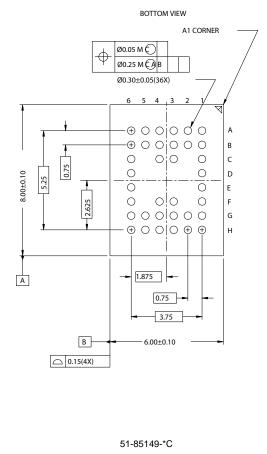
Ordering Code	Package Type	Operating Range	Operating Voltage
CY2XP304BVC	36-lead VFBGA	Commercial, to 400 MHz	3.3V
CY2XP304BVCT	36-lead VFBGA – Tape and Reel	Commercial, to 400 MHz	3.3V
CY2XP304BVI	36-lead VFBGA	Industrial, to 400 MHz	3.3V
CY2XP304BVIT	36-lead VFBGA – Tape and Reel	Industrial, to 400 MHz	3.3V
Lead-free	•		•
CY2XP304BVXC	36-lead VFBGA	Commercial, to 400 MHz	3.3V
CY2XP304BVXCT	36-lead VFBGA – Tape and Reel	Commercial, to 400 MHz	3.3V
CY2XP304BVXI	36-lead VFBGA	Industrial, to 400 MHz	3.3V
CY2XP304BVXIT	36-lead VFBGA – Tape and Reel	Industrial, to 400 MHz	3.3V

## **Package Drawing and Dimensions**

### 36-Lead VFBGA (6 x 8 x 1 mm) BV36A







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# **Document History Page**

Document Title: CY2XP304 High-Frequency Programmable PECL Clock Generation Module Document Number: 38-07589				
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	129898	12/02/03	RGL	New Data Sheet
*A	235868	See ECN	RGL	Updated Jitter spec based on the characterization report
*B	247601	See ECN	RGL/GGK	Changed V <sub>OH</sub> and V <sub>OL</sub> to match the Char Data
*C	300320	See ECN	RGL	Minor Change: Re-phrased the first bullet in the features
*D	413407	See ECN	RGL	Added Lead-free devices Added typical Values